



13281 U.S. PTO

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December 2, 2003

In Affiliation with
Weiss, Moy & Harris, PC
having offices in Arizona and Nevada,
and in Washington, DC with
Rabin & Berdo, PC**Mail Stop Patent Application**

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Attorney Reference: MAE 301

Re: New Patent Application of: Mitsuhiro OGIHARA**Title:** SEMICONDUCTOR EPITAXIAL STRUCTURE AND
SEMICONDUCTOR LIGHT-EMITTING DEVICE

Sir:

Please find attached hereto an application for patent which includes:

- ☒ Specification, Claims and Abstract (22 Pages)
- ☒ 8 Sheets of Formal Drawings (Fig. 1 through Fig. 8)
- ☒ Inventor's Declaration and Power of Attorney (1 Page)
- ☒ Assignment document with cover page (2 Pages)
- ☒ Claim for priority and Priority document
- ☒ Information Disclosure Statement, Form PTO-1449, and copies of 2 cited references
- ☒ Form PTO-2038 (1 Page)
- ☒ Fee (see formula below)

Basic Fee \$770/385 \$ 770.00

Additional Fees:

Total number of claims: 15
in excess of 20: 0 times \$18/9 \$ 0.00Number of independent claims: 2
in excess of 3: 0 times \$86/43 \$ 0.00Multiple Dependent Claims \$290/145 \$ 0.00Recording Fee \$40. \$ 40.00**TOTAL FEES FOR THE ABOVE APPLICATION** \$ **810.00**

In the event there is attached hereto no credit card form PTO-2038 or check, or there is an insufficient amount, please charge the fee to our Account No. 18-0002 and notify us accordingly.

The rights of priority are claimed under 35 USC §119 of Japanese Application No. 2002-350808, filed December 3, 2002.

Respectfully submitted,

Robert H. Berdo, Jr. (Reg. No. 38,075)
(Customer No. 23995)December 2, 2003

Date

RHB:tz

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